

PSMN4R6-60BS,118 Datasheet



DiGi Electronics Part Number	PSMN4R6-60BS,118-DG
Manufacturer	Nexperia USA Inc.
Manufacturer Product Number	PSMN4R6-60BS,118
Description	MOSFET N-CH 60V 100A D2PAK
Detailed Description	N-Channel 60 V 100A (T _c) 211W (T _c) Surface Mount D2PAK

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Manufacturer Product Number:		Manufacturer:	
PSMN4R6-60BS,118		Nexperia USA Inc.	
Series:	-	Product Status:	
FET Type:	N-Channel	Technology:	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	60 V	Current - Continuous Drain (Id) @ 25°C:	100A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	10V	Rds On (Max) @ Id, Vgs:	4.4mOhm @ 25A, 10V
Vgs(th) (Max) @ Id:	4V @ 1mA	Gate Charge (Qg) (Max) @ Vgs:	70.8 nC @ 10 V
Vgs (Max):	±20V	Input Capacitance (Ciss) (Max) @ Vds:	4426 pF @ 30 V
FET Feature:	-	Power Dissipation (Max):	211W (Tc)
Operating Temperature:	-55°C ~ 175°C (Tj)	Mounting Type:	Surface Mount
Supplier Device Package:	D2PAK	Package / Case:	TO-263-3, D2PAK (2 Leads + Tab), TO-263AB
Base Product Number:	PSMN4R6		

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0095	



PSMN4R6-60BS

N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK

Rev. 1 — 22 March 2012

Product data sheet

1. Product profile

1.1 General description

Standard level N-channel MOSFET in a D2PAK package qualified to 175 °C. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High efficiency due to low switching and conduction losses
- Suitable for standard level gate drive sources

1.3 Applications

- DC-to-DC converters
- Load switching
- Motor control
- Server power supplies

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}; T_j \leq 175^\circ\text{C}$	-	-	60	V
I_D	drain current	$T_{mb} = 25^\circ\text{C}$; see Figure 1	[1]	-	100	A
P_{tot}	total power dissipation	$T_{mb} = 25^\circ\text{C}$; see Figure 2	-	-	211	W
T_j	junction temperature		-55	-	175	°C
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_j = 100^\circ\text{C}$; see Figure 12 ; see Figure 13	-	5.98	7	mΩ
		$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; T_j = 25^\circ\text{C}$; see Figure 13	-	3.74	4.4	mΩ
Dynamic characteristics						
Q_{GD}	gate-drain charge	$V_{GS} = 10\text{ V}; I_D = 25\text{ A}; V_{DS} = 30\text{ V}$; see Figure 14 ; see Figure 15	-	14.8	-	nC
$Q_{G(tot)}$	total gate charge		-	70.8	-	nC
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$V_{GS} = 10\text{ V}; T_{j(init)} = 25^\circ\text{C}; I_D = 100\text{ A}$; $V_{sup} \leq 60\text{ V}$; $R_{GS} = 50\Omega$; unclamped	-	-	266	mJ

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain ^[1]		
3	S	source		
mb	D	mounting base; connected to drain		
SOT404 (D2PAK)				

[1] It is not possible to make connection to pin 2

3. Ordering information

Table 3. Ordering information

Type number	Package	Version	
Name	Description		
PSMN4R6-60BS	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

4. Marking

Table 4. Marking codes

Type number	Marking code
PSMN4R6-60BS	PSMN4R6-60BS

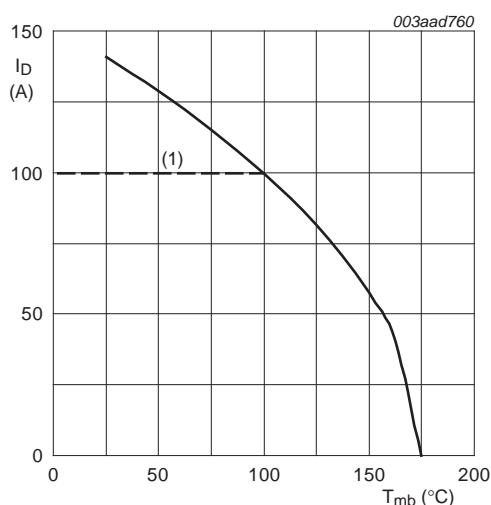
5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

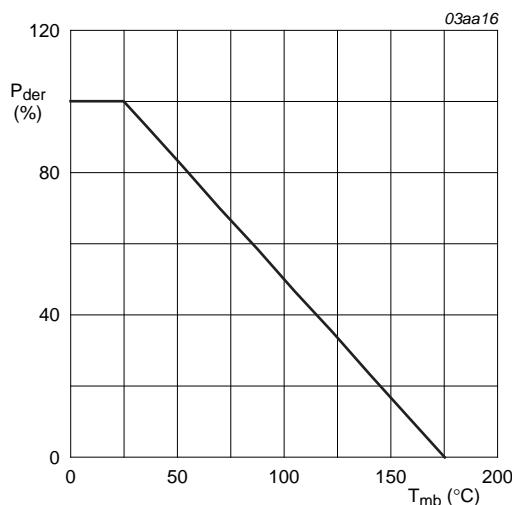
Symbol	Parameter	Conditions	[1]	Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	60	V
V _{DGR}	drain-gate voltage	T _j ≥ 25 °C; T _j ≤ 175 °C; R _{GS} = 20 kΩ		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	T _{mb} = 100 °C; see Figure 1	[1]	-	99.7	A
		T _{mb} = 25 °C; see Figure 1	[1]	-	100	A
I _{DM}	peak drain current	pulsed; t _p = 10 µs; T _{mb} = 25 °C; see Figure 3		-	565	A
P _{tot}	total power dissipation	T _{mb} = 25 °C; see Figure 2		-	211	W
T _{stg}	storage temperature			-55	175	°C
T _j	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain diode						
I _S	source current	T _{mb} = 25 °C	[1]	-	100	A
I _{SM}	peak source current	pulsed; t _p = 10 µs; T _{mb} = 25 °C		-	565	A
Avalanche ruggedness						
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V _{GS} = 10 V; T _{j(init)} = 25 °C; I _D = 100 A; V _{sup} ≤ 60 V; R _{GS} = 50 Ω; unclamped		-	266	mJ

[1] Continuous current is limited by package.



V_{GS} ≥ 10 V; (1) capped at 100 A due to package.

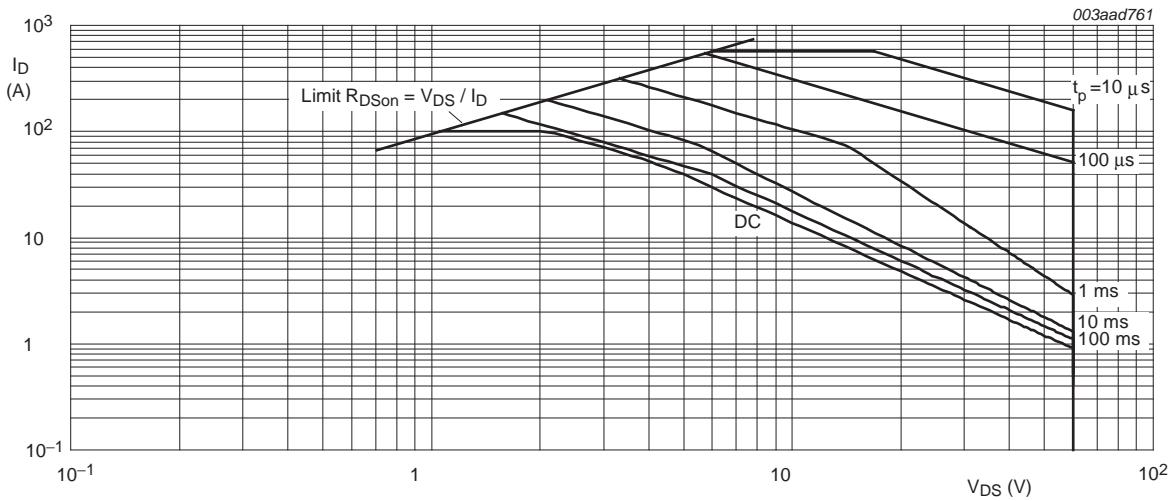
Fig 1. Continuous drain current as a function of mounting base temperature



$$P_{der} = \frac{P_{tot}}{P_{tot}(25^{\circ}\text{C})} \times 100 \%$$

Fig 2. Normalized total power dissipation as a function of mounting base temperature

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PSMN4R6-60BS**N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK**

$T_{mb} = 25^\circ\text{C}$; I_{DM} is a single pulse; (1) capped at 100 A due to package

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j\text{-}mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	0.38	0.71	K/W
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient	minimum footprint; mounted on a printed circuit board	-	50	-	K/W

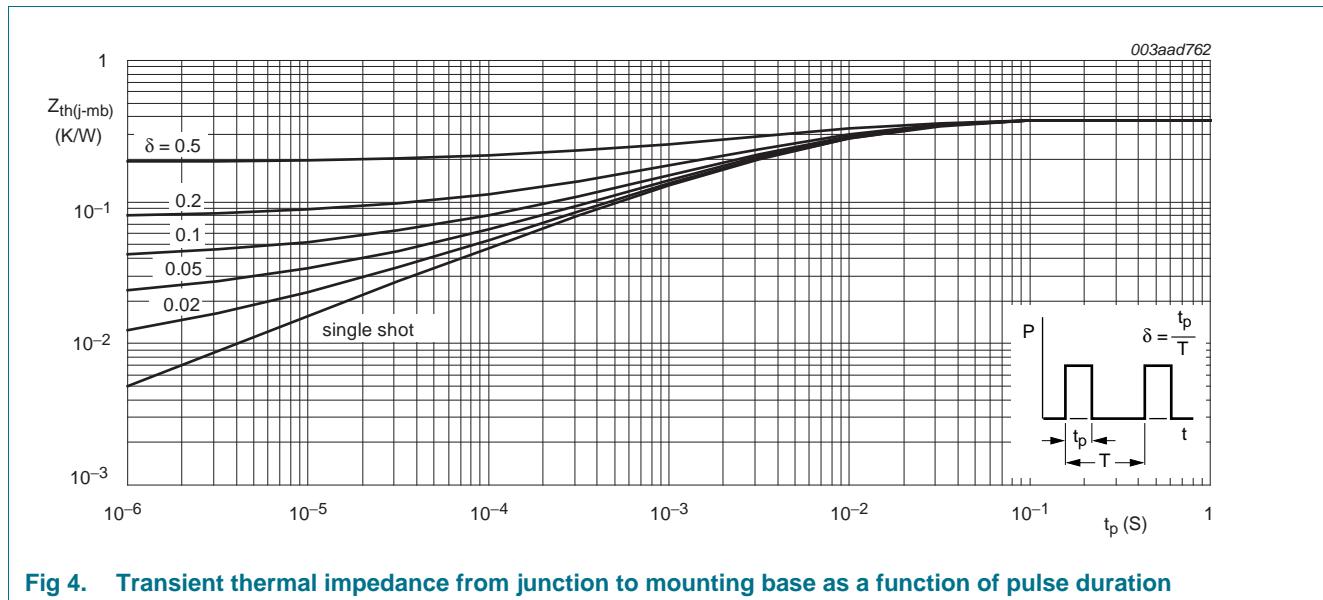


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

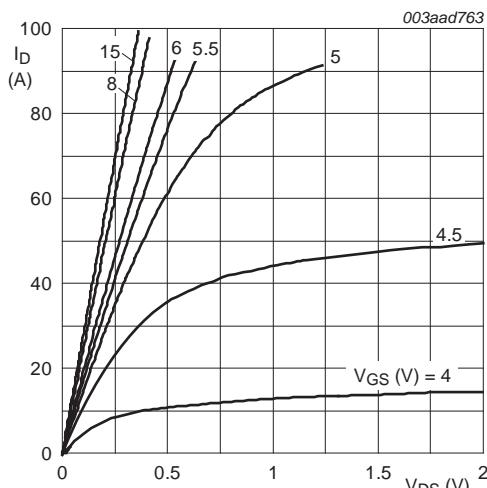
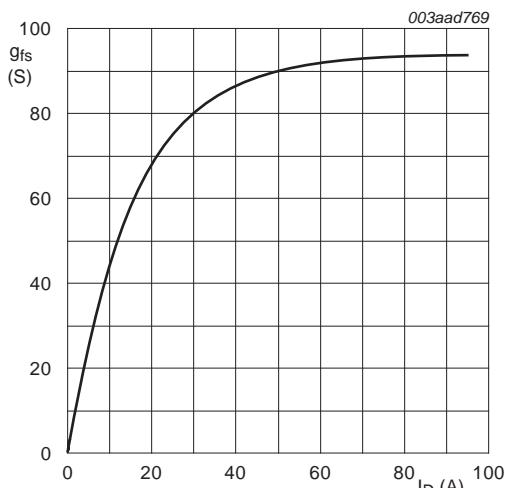
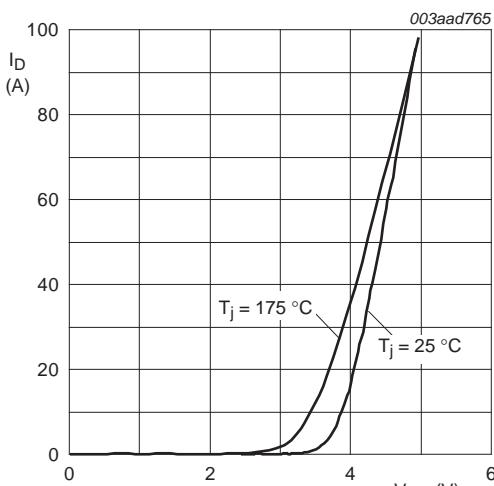
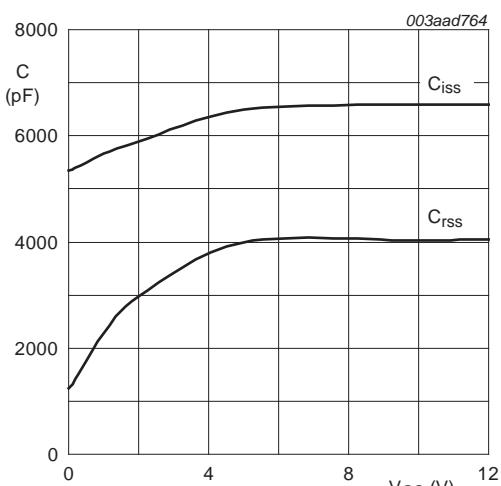
7. Characteristics

Table 7. Characteristics

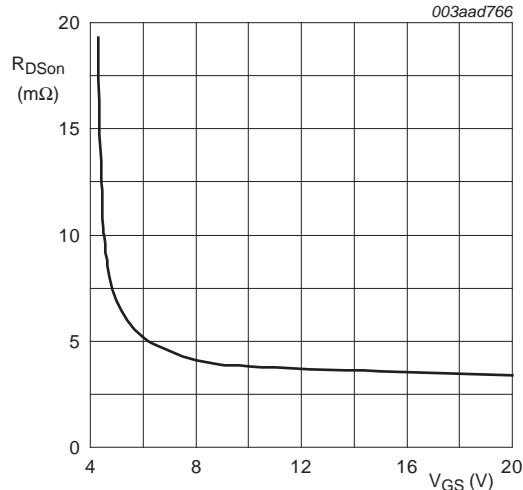
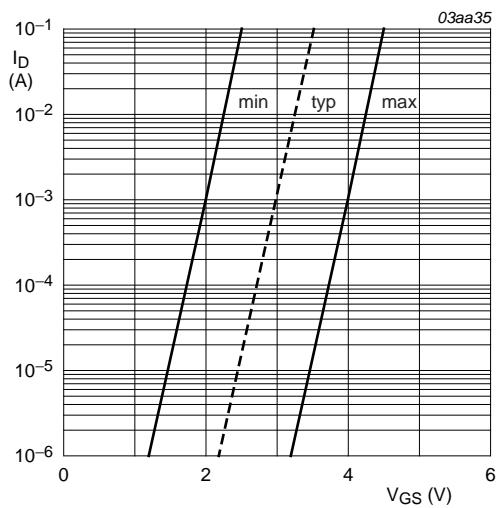
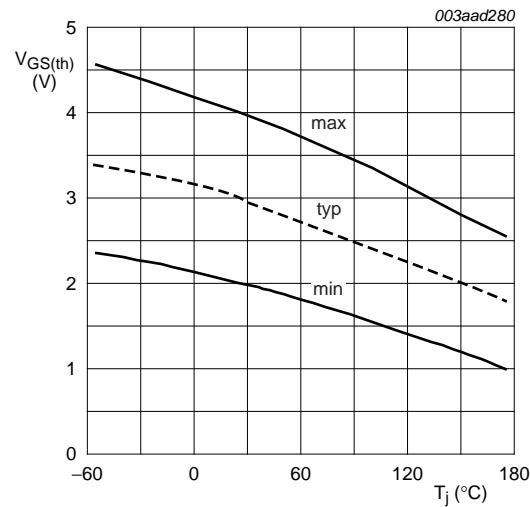
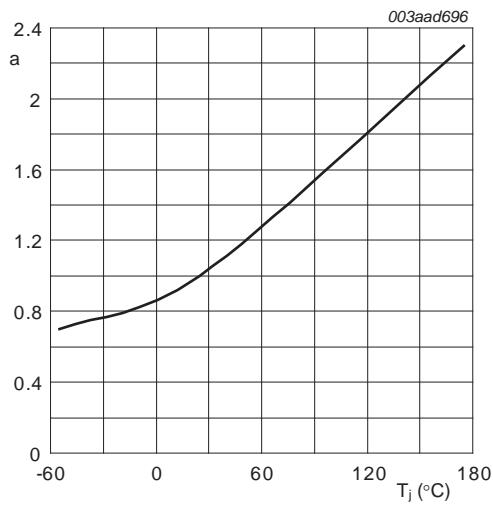
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$ $I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$	54	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C;$ see Figure 10 ; see Figure 11	2	3	4	V
V_{GSth}	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C;$ see Figure 11	-	-	4.8	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175^\circ C;$ see Figure 11	1	-	-	V
I_{DSS}	drain leakage current	$V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25^\circ C$ $V_{DS} = 60 V; V_{GS} = 0 V; T_j = 125^\circ C$	-	0.05	10	μA
I_{GSS}	gate leakage current	$V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25^\circ C$ $V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25^\circ C$	-	10	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 25 A; T_j = 175^\circ C;$ see Figure 12 ; see Figure 13	-	8.6	10.1	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 100^\circ C;$ see Figure 12 ; see Figure 13	-	5.98	7	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C;$ see Figure 13	-	3.74	4.4	$m\Omega$
R_G	gate resistance	$f = 1 MHz$	-	0.79	-	Ω
Dynamic characteristics						
$Q_{G(tot)}$	total gate charge	$I_D = 0 A; V_{DS} = 0 V; V_{GS} = 10 V$ $I_D = 25 A; V_{DS} = 30 V; V_{GS} = 10 V;$	-	63	-	nC
Q_{GS}	gate-source charge	see Figure 14 ; see Figure 15	-	70.8	-	nC
$Q_{GS(th)}$	pre-threshold gate-source charge		-	19.5	-	nC
$Q_{GS(th-pl)}$	post-threshold gate-source charge		-	13.5	-	nC
Q_{GD}	gate-drain charge		-	6	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	$I_D = 25 A; V_{DS} = 30 V;$ see Figure 14 ; see Figure 15	-	4.3	-	V
C_{iss}	input capacitance	$V_{DS} = 30 V; V_{GS} = 0 V; f = 1 MHz;$	-	4426	-	pF
C_{oss}	output capacitance	$T_j = 25^\circ C;$ see Figure 16	-	567	-	pF
C_{rss}	reverse transfer capacitance		-	293	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 30 V; R_L = 1.2 \Omega; V_{GS} = 10 V;$	-	26	-	ns
t_r	rise time	$R_{G(ext)} = 4.7 \Omega$	-	24	-	ns
$t_{d(off)}$	turn-off delay time		-	58	-	ns
t_f	fall time		-	22	-	ns

Nexperia**PSMN4R6-60BS****N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK****Table 7. Characteristics ...continued**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Source-drain diode						
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; see Figure 17	-	0.81	1.1	V
t _{rr}	reverse recovery time	I _S = 25 A; dI _S /dt = -100 A/μs;	-	45	-	ns
Q _r	recovered charge	V _{GS} = 0 V; V _{DS} = 30 V	-	64	-	nC

 $T_j = 25^\circ\text{C}$ **Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values** $T_j = 25^\circ\text{C}; V_{DS} = 10\text{ V}$ **Fig 6. Forward transconductance as a function of drain current; typical values** $V_{DS} > I_D \times R_{DSon}$ **Fig 7. Transfer characteristics: drain current as a function of gate-source voltage; typical values** $f = 1\text{ MHz}; V_{DS} = 0\text{ V}$ **Fig 8. Input and reverse transfer capacitances as a function of gate-source voltage, typical values**

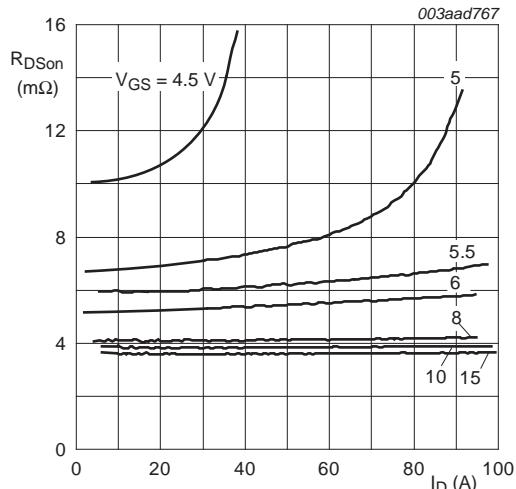
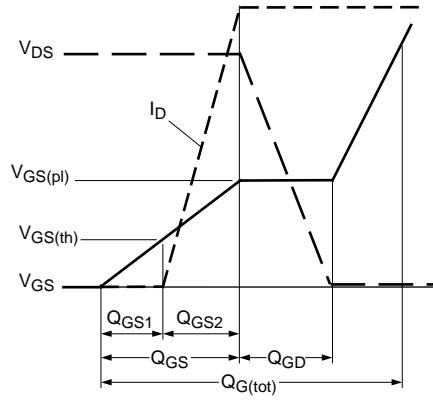
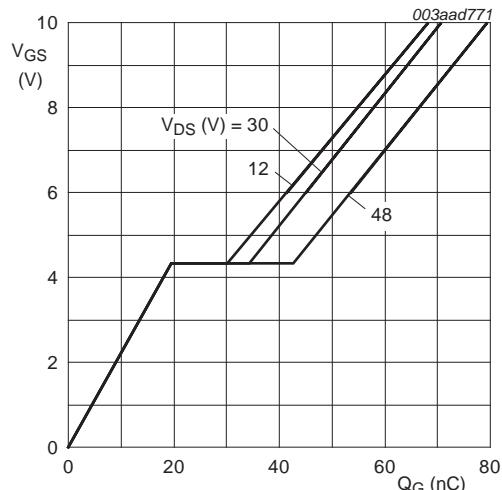
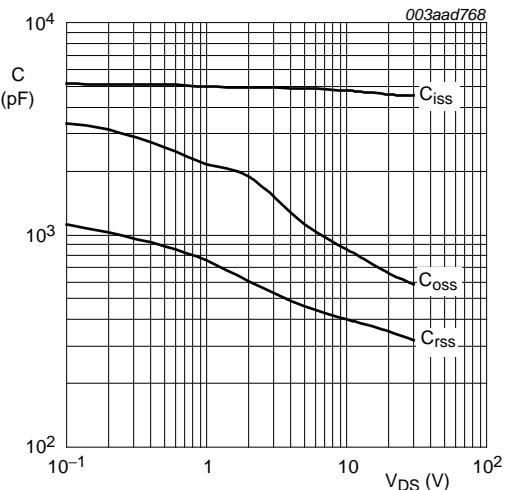
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PSMN4R6-60BS**N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK** $T_j = 25^\circ\text{C}; I_D = 25 \text{ A}$ **Fig 9.** Drain-source on-state resistance as a function of gate-source voltage; typical values $T_j = 25^\circ\text{C}; V_{DS} = 5\text{V}$ **Fig 10.** Sub-threshold drain current as a function of gate-source voltage $I_D = 1 \text{ mA}; V_{DS} = V_{GS}$ **Fig 11.** Gate-source threshold voltage as a function of junction temperature

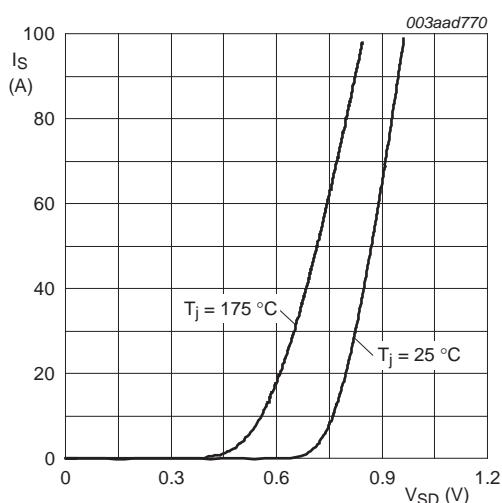
$$a = \frac{R_{DS(on)}}{R_{DS(on)(25^\circ\text{C})}}$$

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature.

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PSMN4R6-60BS**N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK** $T_j = 25^\circ C$ **Fig 13. Drain-source on-state resistance as a function of drain current; typical values****Fig 14. Gate charge waveform definitions** $T_j = 25^\circ C; I_D = 25 A$ **Fig 15. Gate-source voltage as a function of gate charge; typical values** $V_{GS} = 0 V; f = 1 MHz$ **Fig 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values**

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PSMN4R6-60BS**N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK****Fig 17. Source current as a function of source-drain voltage; typical values**

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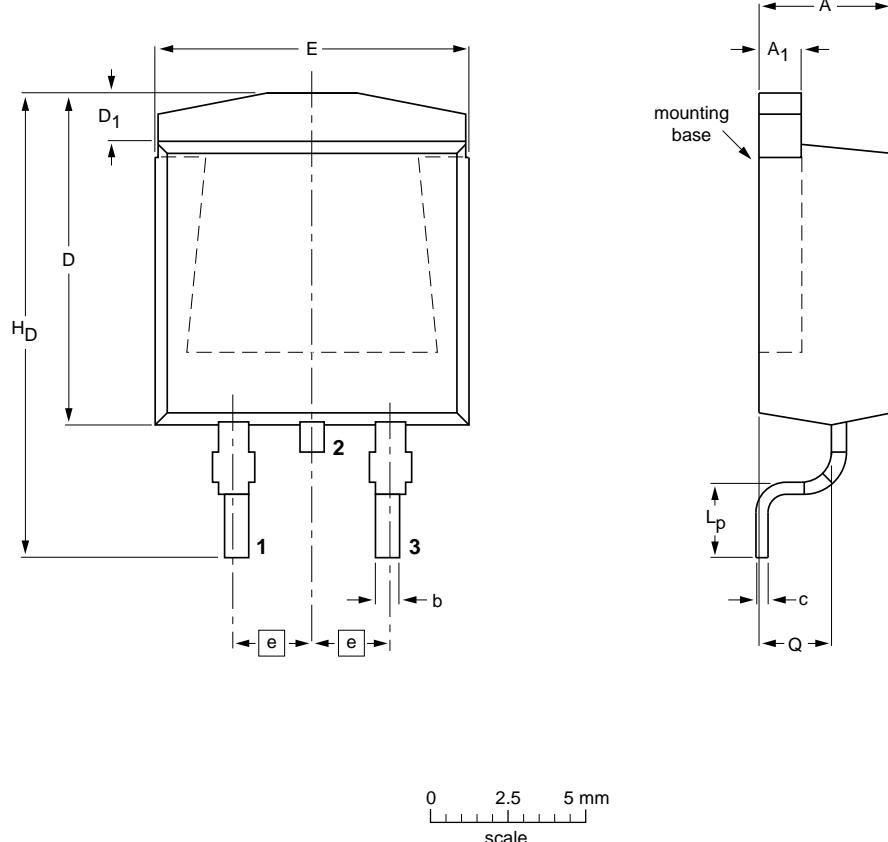
PSMN4R6-60BS

N-channel 60 V, 4.4 mΩ standard level MOSFET in D2PAK

8. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)

SOT404



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	c	$D_{max.}$	D_1	E	e	L_p	H_D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT404						-05-02-11 06-03-16

Fig 18. Package outline SOT404 (D2PAK)

9. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN4R6-60BS v.1	20120322	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status ^[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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For sales office addresses, please send an email to:salesaddresses@nexperia.com

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